

EAST - {10791250 nonlinear gate.wsp.1} X

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124:1226213 with 14
 125:10130 with 34
 126:1758012) straight
 127:(4) 34 with 38
 128:(10) 34 with 2
 129:(11649) 3 near 6 14
 140:(1970282) physical
 141:(11) 39 with 40
 142:(650406) (mask\$4 retic\$4 photoresist photo adj resist)
 143:(148312 with 42
 144:(3143 with 14
 145:(52111 and 5
 146:(39111 and 3
 147:(27) 45 and 46
 148:(1164530) (photoresist photo adj resist)
 149:(17) 47 and 48
 150:(49051) 12 near characteristic
 151:(80) 2 with 50
 152:(10) 48 same 51
 153:(10) 42 same 51
 154:(11) 42 and 51

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May 2005

U	Document	Document	Title	Current	Current	I	Brevets	S	C	P	Image	Def P
1	<input type="checkbox"/> Celafut; Da	US 622018	2001 9 Very high aspect ratio semiconductor	257/24	257/392;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 622018
2	<input type="checkbox"/> Bostoker; M	US 577360	1998 13 Hexagonal field programmable gate ar	257/31	257/401;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 57736
3	<input type="checkbox"/> Uidow; Alex	US 5742087	1998 18 High power MOSFET with low on-resista	257/34	257/339;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 5742087
4	<input type="checkbox"/> Tokura; Nor	US 601573	2000 2 Production method of a vertical type M	438/27	257/E21.41		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 601573
5	<input type="checkbox"/> Restoker; M	US 5631581	1997 17 Microelectronic integrated circuit incl	328/10	257/206;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 5631581
6	<input type="checkbox"/> Bulucea; C	US 882795	2003 4 Trench DMOS power transistor with fiel	257/32	257/320;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 882795
7	<input type="checkbox"/> Okabe; Yas	US 6608179	2003 37 Vertical type MOSFET	257/33	257/331;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6608179
8	<input type="checkbox"/> Blanchard; US	6048473	2000 15 Structure and process for reducing the	257/34	257/342;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6048473
9	<input type="checkbox"/> Ayala; Chris	US 595658	1999 11 Current limiting circuit with continuous	439/20	257/328;		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 595658
10	<input type="checkbox"/> Bulucea; C	US 589735	1999 2 Method of manufacturing insulated ga	438/27	257/E29.2		<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 589735